MOSFET – Power, Single, P-Channel, TSOP-6

-30 V, -4.7 A

Features

- Leading -30 V Trench Process for Low R_{DS(on)}
- Low Profile Package Suitable for Portable Applications
- Surface Mount TSOP-6 Package Saves Board Space
- Improved Efficiency for Battery Applications
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb-Free Package is Available

Applications

- Battery Management and Switching
- Load Switching
- Battery Protection

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	-30	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain Cur-	Steady	$T_A = 25^{\circ}C$	I _D	-3.7	А
rent (Note 1)	State	T _A = 85°C		-2.7	
	t ≤ 5 s	$T_A = 25^{\circ}C$		-4.7	
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	P _D	1.25	W
	t ≤ 5 s			2.0	
Continuous Drain Cur-	Steady	$T_A = 25^{\circ}C$	I _D	-2.6	А
rent (Note 2)	State	$T_A = 85^{\circ}C$		-1.9	
Power Dissipation (Note 2)		$T_A = 25^{\circ}C$	P _D	0.63	W
Pulsed Drain Current	tp =	: 10 μs	I _{DM}	-15	А
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to 150	°C
Source Current (Body Diode)			ا _S	-1.7	А
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

THERMAL RESISTANCE RATINGS

Rating	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	R_{\thetaJA}	100	°C/W
Junction-to-Ambient – t \leq 5 s (Note 1)	$R_{\theta JA}$	62.5	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	200	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in sq pad size

(Cu area = 1.127 in sq [1 oz] including traces).

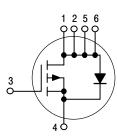


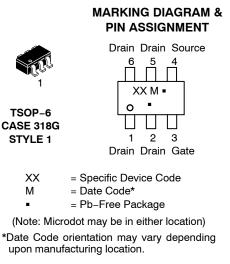
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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
-30 V	38 mΩ @ −10 V	-4.7 A
-00 V	68 mΩ @ −4.5 V	







ORDERING INFORMATION

See detailed ordering and shipping information ion page 6 of this data sheet.

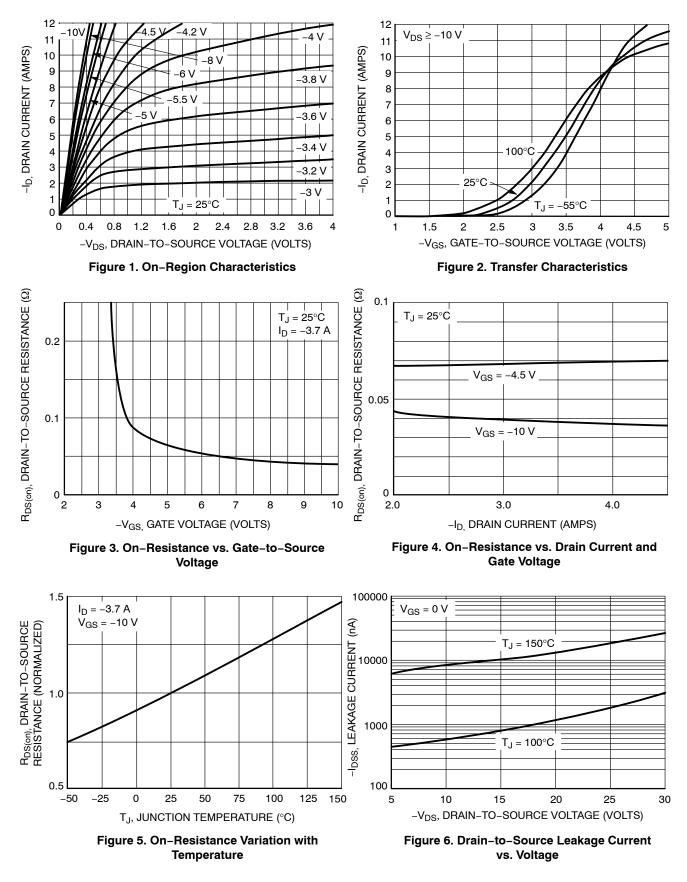
2. Surface-mounted on FR4 board using the minimum recommended pad size (Cu area = 0.006 in sq).

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = -250 μ A		-30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				-17		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V_{c}$	$T_J = 25^{\circ}C$			-1.0	μΑ
		V _{GS} = 0 V, V _{DS} = -24 V	T _J = 125°C			-100	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V ₀	_{GS} = ±20 V			±100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= -250 μA	-1.0		-3.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				5.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = -10 V,	I _D = -3.7 A		38	60	mΩ
		V _{GS} = -4.5 V,	I _D = -2.7 A		68	110	
Forward Transconductance	9 FS	V _{DS} = -10 V,	I _D = -3.7 A		6.0		S
CHARGES, CAPACITANCES AND GATE RE	SISTANCE						
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = -15 V			750		pF
Output Capacitance	C _{OSS}				140		1
Reverse Transfer Capacitance	C _{RSS}				105		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = -10 V, V _{DD} = -15 V, I _D = -3.7 A			15.25	32	nC
Threshold Gate Charge	Q _{G(TH)}				0.8		
Gate-to-Source Charge	Q _{GS}				2.6		
Gate-to-Drain Charge	Q _{GD}				3.4		
SWITCHING CHARACTERISTICS, VGS = -1	0 V (Note 4)						
Turn-On Delay Time	t _{d(ON)}				9.0	17	ns
Rise Time	t _r	V_{GS} = -10 V, V_{DD} = -15 V, I_{D} = -1.0 A, R_{G} = 6.0 Ω			9.0	18	
Turn-Off Delay Time	t _{d(OFF)}				38	85	
Fall Time	t _f				22	45	
SWITCHING CHARACTERISTICS, VGS = -4	.5 V (Note 4)						
Turn-On Delay Time	t _{d(ON)}				11	20	ns
Rise Time	t _r	V _{GS} = -4.5 V, V	י _{חח} = –15 V,		15	28	
Turn-Off Delay Time	t _{d(OFF)}	$I_D = -1.0 \text{ A}, R_G = 6.0 \Omega$			28	56	
Fall Time	t _f				22	50	
DRAIN - SOURCE DIODE CHARACTERIST	CS	-					
Characteristic	Symbol	Test Condition		Min	Тур	Мах	Unit
Forward Diode Voltage	V _{DS}	$V_{GS} = 0 V, I_{S} = -1.0 A T_{J} = 25^{\circ}C T_{J} = 125^{\circ}C$		-0.76	-1.2	V	
				-0.60		1	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V dI _S /dt = 100 A/µs, I _S = -1.0 A			17	40	ns
Charge Time	t _a				9.0		1
Discharge Time	t _b				8.0		1
Reverse Recovery Charge	Q _{RR}				8.0		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 4. Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)





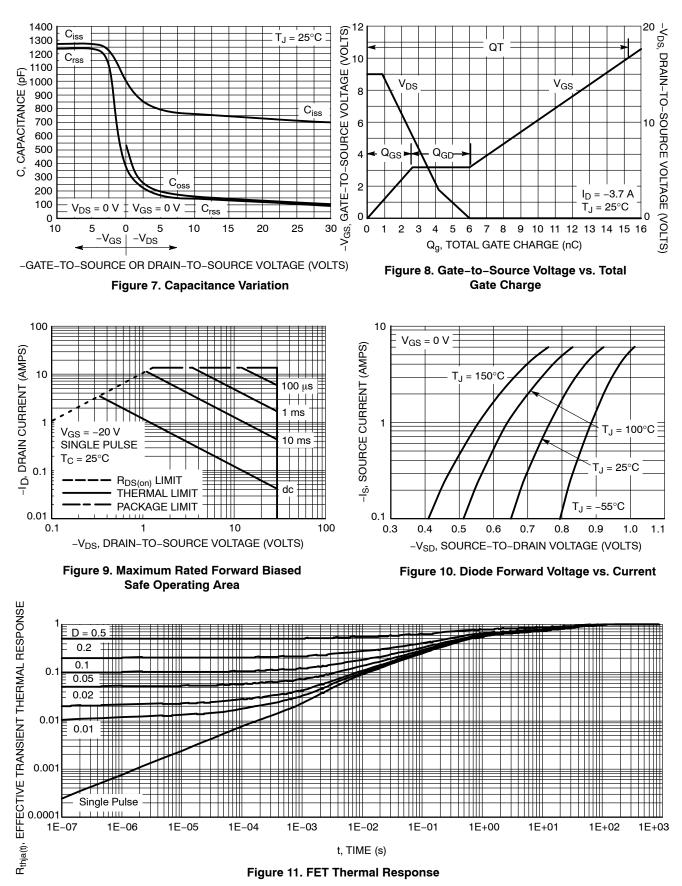


Table 1. ORDERING INFORMATION

Part Number	Marking (XX)	Package	Shipping [†]
NTGS4111PT1	TG	SC-88	3000 / Tape & Reel
NTGS4111PT1G	TG	SC-88 (Pb-Free)	3000 / Tape & Reel
NVGS4111PT1G	VTG	SC–88 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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TSOP-6 CASE 318G-02 ISSUE V DATE 12 JUN 2012 SCALE 2:1 NOTES: D 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. 2 Η MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D 4 ¥ 12 4 GAUGE E1 Е AND E1 ARE DETERMINED AT DATUM H. 5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE. 2 4 MILLIMETERS М NOTE 5 b DIM MIN NOM MAX 0.90 1.10 DETAIL Z Α 1.00 A1 0.01 0.06 0.10 b 0.25 0.38 0.50 с 0.10 0 18 0.26 D 2.90 3.00 3.10 С Е 2.50 2.75 Α 3.00 $|\cap$ 0.05 E1 1.30 1.50 1.70 e L 0.85 0.95 1.05 0.40 0.20 0.60 Δ1 L2 M 0.25 BSC DETAIL Z 10° 0 STYLE 2: PIN 1. EMITTER 2 2. BASE 1 STYLE 3: PIN 1. ENABLE 2. N/C STYLE 4: PIN 1. N/C 2. V in STYLE 5: PIN 1. EMITTER 2 2. BASE 2 STYLE 6: PIN 1. COLLECTOR 2. COLLECTOR STYLE 1: PIN 1. DRAIN 2. DRAIN COLLECTOR 1 EMITTER 1 3. GATE 4. SOURCE З. 3. R BOOST 4. Vz 3. NOT USED 4. GROUND 3. COLLECTOR 1 4. EMITTER 1 3. BASE 4. EMITTER 4. 5. ENABLE 6. LOAD 5. COLLECTOR 6. COLLECTOR 5. DRAIN 5. BASE 2 5. V in 5. BASE 1 6. V out 6. COLLECTOR 2 6. COLLECTOR 2 6. DRAIN STYLE 10: STYLE 11: STYLE 8: STYLE 9: STYLE 12: STYLE 7 PIN 1. COLLECTOR PIN 1. Vbus PIN 1. LOW VOLTAGE GATE PIN 1. D(OUT)+ PIN 1. SOURCE 1 PIN 1. I/O 2. DRAIN 2 2. GROUND 2. COLLECTOR 2. D(in) 2. DRAIN 2. GND 3. D(in)+ 4. D(out)+ 3. SOURCE 4. DRAIN 3. D(OUT)-4. D(IN)-3. BASE DRAIN 2 3. I/O З. 4 N/C 4 I/O 4 SOURCE 2 5. COLLECTOR 5. D(out) 6. GND 5. 5. VBUS 6. D(IN)+ 5. GATE 1 6. DRAIN 1/GATE 2 5. VCC 6. I/O DRAIN 6. HIGH VOLTAGE GATE 6. EMITTER STYLE 13: PIN 1. GATE 1 STYLE 14: PIN 1. ANODE STYLE 15: PIN 1. ANODE STYLE 16: PIN 1. ANODE/CATHODE STYLE 17: PIN 1. EMITTER 2. SOURCE 2 2. SOURCE 2. SOURCE 2. BASE 2. BASE 3 EMITTER 3 ANODE/CATHODE 3. GATE 2 3 GATE 3 GATE 4. DRAIN 2 4. CATHODE/DRAIN 4. DRAIN 4 COLLECTOR ANODE 5. CATHODE/DRAIN CATHODE 5. SOURCE 1 5. N/C 5. ANODE 5. DRAIN 1 6. CATHODE/DRAIN 6. CATHODE CATHODE COLLECTOR 6. 6. 6. GENERIC RECOMMENDED **MARKING DIAGRAM*** SOLDERING FOOTPRINT* 0.60 XXXAYW= XXX M= 0 o 1LI 6X 3.20 IC STANDARD 0.95 XXX = Specific Device Code XXX = Specific Device Code А =Assembly Location Μ = Date Code Y = Pb-Free Package = Year W = Work Week 0.95 = Pb-Free Package PITCH DIMENSIONS: MILLIMETERS *This information is generic. Please refer to device data *For additional information on our Pb-Free strategy and soldering sheet for actual part marking. Pb-Free indicator, "G" details, please download the ON Semiconductor Soldering and or microdot "•", may or may not be present. Some Mounting Techniques Reference Manual, SOLDERRM/D. products may not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ASB14888C Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

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